THE UNITED STATES PATENT AND TRADEMARK OFFICE

REVOCATION AND NEW POWER OF ATTORNEY AND CHANGE OF CORRESPONDENCE ADDRESS

I, Dr. Graham Fisher, Director of Intellectual Property of MEMC Electronic Materials, Inc., the Assignee of the entire right, title, and interest in the U.S. Patent Application(s) and/or Patent(s) identified on the attached Schedule A, hereby revoke all previous powers of attorney or authorizations of agent given and do hereby appoint the attorneys or agents associated with the following Customer Number, with full power of substitution and revocation, to prosecute and transact all business in the Patent and Trademark Office connected therewith for the U.S. Patent Application(s) and/or Patent(s) listed in the attached Schedule A:

Customer Number: 76681

Please direct all correspondence in connection with said U.S. Patent Application(s) and/or Patent(s) to:

Customer Number: 76681

Respectfully submitted

100/

Dr. Graham Fisher
Director of Intellectual Property
MEMC Electronic Materials, Inc.

THE UNITED STATES PATENT AND TRADEMARK OFFICE

STATEMENT UNDER 37 CFR 3.73(b)

MEMC Electronic Materials, Inc., a Delaware Corporation, pursuant to 37 CFR 3.73(b), hereby states that it is the Assignee of the entire right, title, and interest in U.S. Patent Application(s) and/or Patent(s) on the attached Schedule A.

The entire rights, title, and interest in the aforementioned Patent Application(s) and/or Patent(s) were conveyed to MEMC Electronic Materials, Inc. via Assignment(s) recorded with the United States Patent and Trademark Office at the Reel/Frame Numbers on the attached Schedule A.

The undersigned, Dr. Graham Fisher, Director of Intellectual Property, has full authorization to act on behalf of Assignee MEMC Electronic Materials, Inc.

Respectfully submitted,

Date: 5/13/2008

Dr Graham Fisher

Director of Intellectual Property
MEMC Electronic Materials, Inc.

APPENDIX A Owned by MEMC Electronic Materials, Inc.

ATTORNEY REFERENCE	CONF. NO	PUBLICATION NO. & DATE	SERIAL NO. FILING DATE	PATENT NO. ISSUE DATE	CURRENT OWNER/ ASSIGNEE	REEL AND FRAME NO.	шле
AEMC2458.2	1288	US-2003-0118081-A1 6/26/2003	10,280,229 9/50,2002	6,652,648	MEMC Electronic Materials, Inc.	Continuation of D9/853,232 which is a continuation of US/344,036 recorded at 010481/0004	PROCESS FOR GROWING A SILIODN CRYSTAL SEGMENT SUBSTANTIALY FREE FROM AGGLOMERATED INTRINSIC POINT DEFECTS WHICH ALLOWS FOR VARIABILITY IN THE FROGESS CONDITIONS
1EMC2462.1	7225	US-2002-0086539-A1 7/14/2002	10/022,967	7,008,874	MEMC Electronic Materials, Inc.	012722/0205	PROCESS FOR RECLAIMING SEMICONDUCTOR WAFERS AND RECLAIMED WAFERS
dEMC2464	5164	US-2002-0004305-A1 1/10/2802	09/481,080	6,376,395	MEMC Electronic Materials, Inc.	010697/0232	SEMICONDUCTOR WAFER MANUFACTURING PROCESS
EMC2466.1	6259		09/691,994 10/19/2000	8,602,77 228,803,822	MEMC Electronic Materials, Inc.	Division of 09/838,826 recorded at 010132/0716	Division of 09(838)888 ELECTRICAL RESISTANCE HEATER AND METHOD FOR 1010(32/07/16)
JEMC2471	9361	US-2001-0008114.A1 7/19/2001	09/344,709 6/25/1989	6,328,795 12/11/2001	MEMC Electronic Materials, Inc.	010198/0955	PROCESS FOR GROWTH OF DEFECT FREE SILICON CRYSTALS OF ARBITRARILY LARGE DIAMETERS
SEMO24711	1,089	US-2002-0092480-A1 7:18/2002	10,025,540	6,582,123 5/13/2003	MEMC Electronic Materials, Inc.	Continuation of 09/344,709 recorded at 010/198/0955	PROCESS FOR GROWING DEFECT-FREE SLICON WHEREIN THE GROWN SELICON IS GOOLED IN A SEPARATE OF AMBER
E4024712	3364	05-2904-0003770-A1 10,437,141 1672004 67382004	10,497,141 5/13/2003	6,913,847 745/2005	MENC Electronic Materials, Inc.	Continuation of 10/035,540 which is a 6 continuation of 109/344,709 recorded 4 at 010188/0955	monitorition of process for copy, NG A Siglicon INGOT HANNIGA (POSS-50 with a process for copy, NG A Siglicon INGOT HANNIGA (POSS-50 with a process of copy, NG A Siglicon INGOT HANNIGA (POSS-50 WITH EE POSS-40 WITH A SIG
4EMC2477	9073		09.258,618 7/19/1399	6,114,245 9,5/2000	MEMC Electronic Materials, Inc.	Continuation of 08915,975 recorded at 66310797	METHOD OF PROCESSING SEMICONDUCTOR WAFERS
8744.181 MEMC2489)	3258		6881./1/8 059/996/60	6,828,690 1,777,71	MEMC Electronic: Materials, Inc.	0102250266	NON-LINIFORM MINORITY CARRIER LIFETIME DISTRIBUTIONS IN HIGH PERFORMANCE SILICON POWER DEVICES
AEMC2489.1	1231	USZ005-0006796 A1 1/13/2005	10/911,965 8/5/2004	7,242,037 7/10/2007	MEMC Electronic Materials, fine	Division of 09/366,850 retorded at 04/0225/0266	DINSHAD OF SERVICE BEST INDICAL LINE OR M. MINORITY CARRIER LIFETIME DISTRIBUTION PROMOBE OF THE CONTRIBUTION PROM
AEMO2493	3777		09,421,167 10/19/1999	6,208,611	MENO Electronic Materials Inc	0103440075	METHOD OF CONTROLLING GROWTH OF A SEMICONDUCTOR GRYSTAL TO AUTOMATICALLY TRANSITION FROM TAPER GROWTH TO TARGET DIAMETER GROWTH
AEMC2495	1207		09/979,383 8/23/1999	6,336,969 1/8/2002	MEMC Electronic Materials, Inc.	01029670838	NON-OXYGEN PRECIPITATING CZOCHRAŁSKI SILICON WAFERS